# Ultra High Dynamic Range

# **Monolithic Amplifier**

**PGA-102+** 

#### **50**Ω 0.05 to 6 GHz

## **The Big Deal**

- High IP3
- Broadband High Dynamic Range without external Matching Components



SOT-89 PACKAGE

## **Product Overview**

PGA-102+ (RoHS compliant) is an advanced wideband amplifier fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PGA-102+ has good input and output return loss over a broad frequency range without the need for external matching components and has demonstrated excellent reliability. It has repeatable performance from lot to lot and is enclosed in a SOT-89 package for very good thermal performance.

## **Key Features**

Feature	Advantages		
Broad Band: 0.05 to 6.0 GHz	Broadband covering primary wireless communications bands: Cellular, PCS, LTE, WiMAX		
High IP3 Versus DC power Consumption: 33 dBm typical at 2 GHz at +3.3V Supply Voltage and only 83mA	The PGA-102+ provides good IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being typically 15 dB above the P 1dB point. This feature makes this amplifier ideal for use in:  • Driver amplifiers for complex waveform up converter paths  • Drivers in linearized transmit systems  • Secondary amplifiers in ultra High Dynamic range receivers		
No External Matching Components Required	Unlike competing products, Mini-Circuits PGA-102+ provides Input and Output Return Loss of 16-19 dB up to 4 GHz without the need for any external matching components		
Low Noise Figure: 2.3 dB up to 0.8 GHz	A unique feature of the PGA-102+ which separates this design from all competitors is the low noise figure performance in combination with the high dynamic range.		

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# **Monolithic Amplifier**

0.05-6 GHz

#### **Product Features**

- 3.3V, 83mA operation
- High IP3, 33 dBm typ. at 2 GHz
- Gain, 14.0 dB typ. at 2 GHz
- P1dB 17.5 dBm typ. at 2 GHz
- Low noise figure, 2.4dB at 2 GHz
- No external matching components required



Generic photo used for illustration purposes only

CASE STYLE: DF782

PGA-102+

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

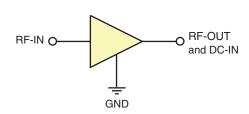
## **Typical Applications**

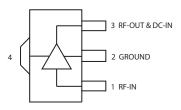
- Base station infrastructure
- Portable Wireless
- CATV & DBS
- MMDS & Wireless LAN
- LTE

#### **General Description**

PGA-102+ (RoHS compliant) is an advanced wideband amplifier fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PGA-102+ has good input and output return loss over a broad frequency range without the need for external matching components. It has repeatable performance from lot to lot and is enclosed in a SOT-89 package for very good thermal performance.

#### simplified schematic and pin description





Function	Pin Number	Description	
REIN I I		RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.	
RE-OUT and DC-IN 3 capacitor is necessary for proper operation. An RF choke is needed to fe		RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit", Fig. 2	
GND	GND 2,4 Connections to ground. Use via holes as shown in "Suggested Layout for P to reduce ground path inductance for best performance.		

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### Electrical Specifications<sup>1</sup> at 25°C, 50Ω and 3.3V, unless noted

Parameter	Condition (GHz)	Min.	Тур.	Max.	Units
Frequency Range	, ,	0.05		6	GHz
Gain	0.05	_	17.7		dB
dan	0.8	14.4	15.9	17.4	
	2.0	_	14.0	_	
	3.0	_	12.5	_	
	4.0	_	11.5	_	
	6.0		10.4		
Input Return Loss	0.05	_	14.0	_	dB
	0.8	15	18.4	_	
	2.0	_	12.4	_	
	3.0	_	10.5	_	
	4.0	_	9.4	_	
	6.0	_	6.7		
Output Return Loss	0.05		18.3	_	dB
	0.8	15 	18.6	_	
	2.0 3.0	_	17.6 17.1	_	
	4.0	_	17.1	_	
	6.0		11.0	_	
Reverse Isolation	2.0	_	21.9		dB
Output Power @1 dB compression	0.05	_	17.6		dBm
Output Power @ r db compression	0.8	16.0	17.4	_	dBiii
	2.0	_	17.5	_	
	3.0	_	17.5	_	
	4.0	_	17.3	_	
	6.0	_	16.5	_	
Output IP3	0.05		30.8		dBm
•	0.8		32.7		
	2.0		33.0		
	3.0		33.0		
	4.0		33.4		
	6.0		33.2		
Noise Figure	0.05		2.1		dB
	0.8		2.3		
	2.0		2.4		
	3.0		2.8		
	4.0		3.0		
Device Operating Voltage	6.0	3.1	3.9	3.5	V
Device Operating Voltage Device Operating Current		60	83	120	mA
Device Operating Current Device Current Variation vs. Temperature		00	49	120	μΑ/°C
Device Current Variation vs. Temperature  Device Current Variation vs Voltage			0.066		mA/mV
Thermal Resistance, junction-to-ground lead			73		°C/W
mermai nesistance, junction-to-ground lead			/3		-0/٧٧

<sup>1.</sup> Measured on Mini-Circuits Characterization test board TB-313. See Characterization Test Circuit (Fig.

#### **Absolute Maximum Ratings**

Parameter	Ratings		
Operating Temperature (ground lead)	-40°C to 85°C		
Storage Temperature	-65°C to 150°C		
Operating Current at 3.3V	300 mA		
Power Dissipation	1.0 W		
Input Power (CW)	28 dBm		
DC Voltage on Pin 3	5.5 V		

Permanent damage may occur if any of these limits are exceeded.

Electrical maximum ratings are not intended for continuous normal operation.

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#### **Characterization Test Circuit**

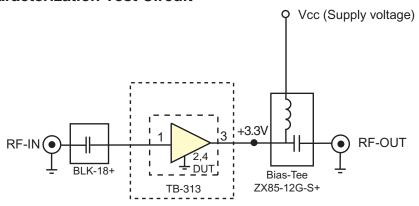
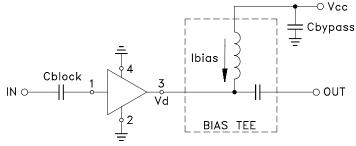


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT tested on Mini-Circuits Characterization test board TB-313) Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions:

- 1. Gain and Return loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 10 MHz apart, 2.5 dBm/tone at output.

#### **Recommended Application Circuit**



Cblock=0.001µF, Bias-Tee=TCBT-14+, Cbypass=0.1µF

Fig 2. Evaluation board includes case, connectors, and components soldered to PCB

## **Product Marking**



Marking may contain other features or characters for internal lot control

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Additional Detailed Technical Information additional information is available on our dash board. To access this information click here				
	Data Table			
Performance Data	Swept Graphs			
	S-Parameter (S2P Files) Data Set (.zip file)			
Case Style	DF782 (SOT 89) Plastic package, exposed paddle lead finish: matte-tin			
Tape & Reel	F55			
Standard quantities available on reel	7" reels with 20, 50, 100, 200, 500 or 1K devices			
Suggested Layout for PCB Design	PL-313			
Evaluation Board	TB-596-1+			
Environmental Ratings	ENV08T1			

## **ESD Rating**

Human Body Model (HBM): Class 1B (500 to <1000V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1(50V) in accordance with ANSI/ESD STM5.2-1999



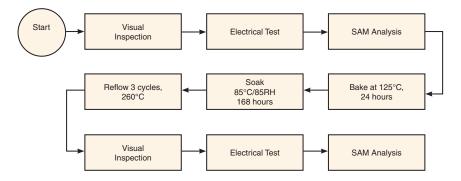
#### Attention

Observe precautions for handling electrostatic sensitive devices

#### **MSL Rating**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

#### **MSL Test Flow Chart**



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